

Investigation on Thermal and Electrical Characteristics of MgB₂ Magnet Using Partial-Insulation Winding Technique

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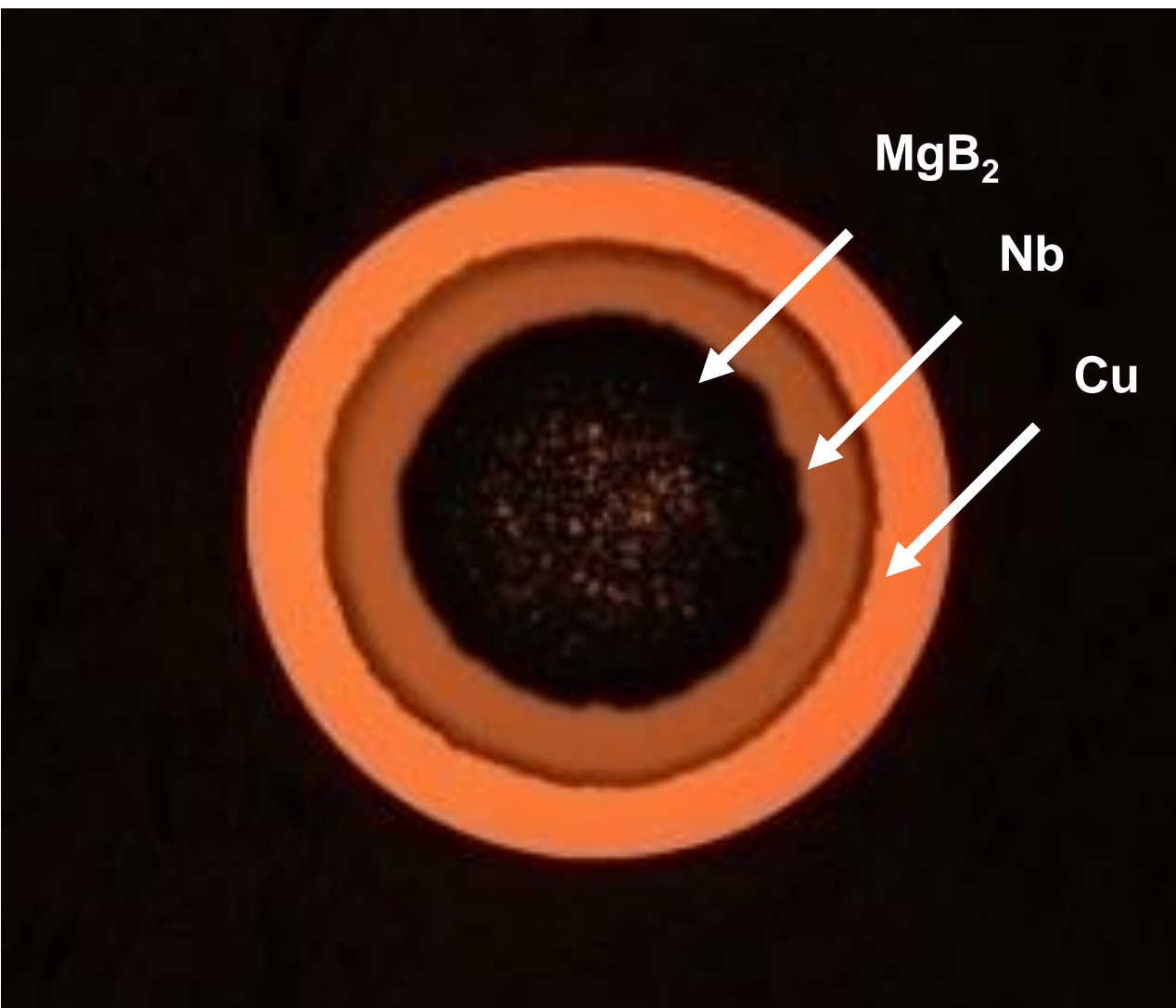
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Abstract

It is generally agreed that the development of a self-protective MgB₂ magnet may not be achieved because of the slow normal-zone propagation velocity of the MgB₂ wires, compared to their low-temperature superconductor counterparts. However, the use of the no-insulation (NI) winding technique can allow the MgB₂ magnet to be self-protecting, because the excessive heat and current generated by local quenching can be automatically bypassed through the uninsulated turns. Nevertheless, to utilize the NI winding technique for large-scale superconducting magnets such as whole-body MRI magnets, it is essential to ameliorate the charging/discharging delays observed in the NI windings. As an alternative solution, this study examines a partially insulated (PI) MgB₂ magnet that employs layer-to-layer insulations only, in the absence of turn-to-turn insulations. A monofilament MgB₂ wire manufactured by Kiswire Advanced Technology Co. Ltd., was used for the fabrication of the PI MgB₂ magnet. The charge-discharge and over-current characteristics of the PI MgB₂ magnet were investigated to demonstrate the feasibility of employing the PI winding technique to develop a self-protective MgB₂ MRI magnet with fast charging/discharging rates.

Experimental setup

★ MgB₂ wires



< Optical microscope image of the MgB₂ wire fabricated by KAT Ltd. >

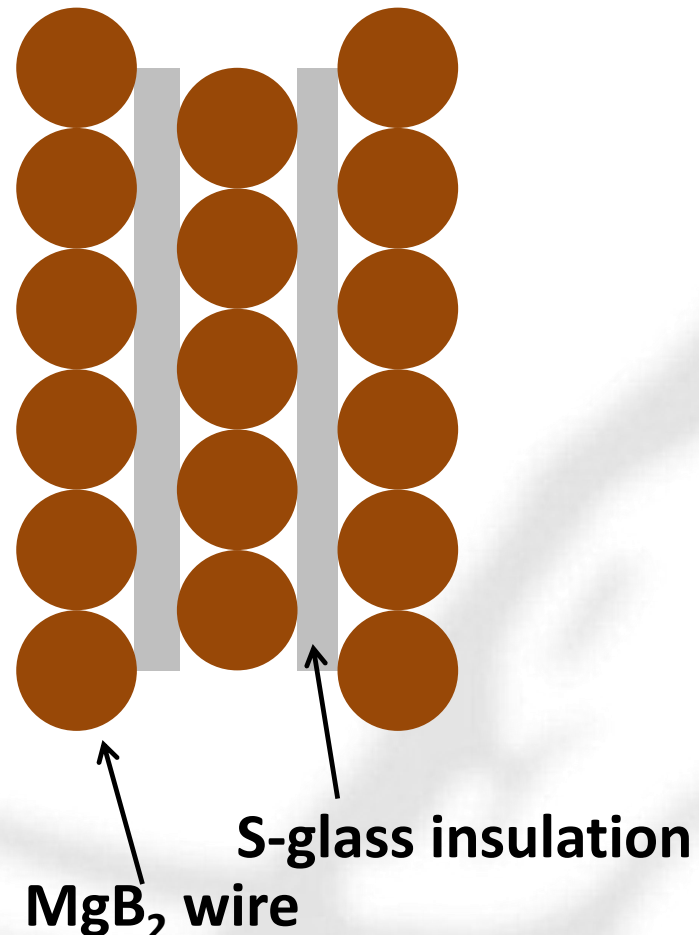
< Specifications of MgB₂ wire >

Parameters		Values
Company		Kiswire Advanced Technology
Packing density	[g/cm ³]	0.31
Diffusion barrier		Niobium
Stabilizer		Copper
Filament type		Monofilament
Diameter	[mm]	1.03
Condition		Un-reacted
Non-Sc/Sc		2.09
Heat treatment temperature	[°C]	675
Heat treatment time	[hr]	1
<i>I</i> _c @ 4.2 K, 4 T	[A]	283
<i>I</i> _c @ 4.2 K, 5 T	[A]	138
<i>I</i> _c @ 4.2 K, 6 T	[A]	66

★ Prototype PI MgB₂ magnet

< Specifications of the prototype PI MgB₂ magnet >

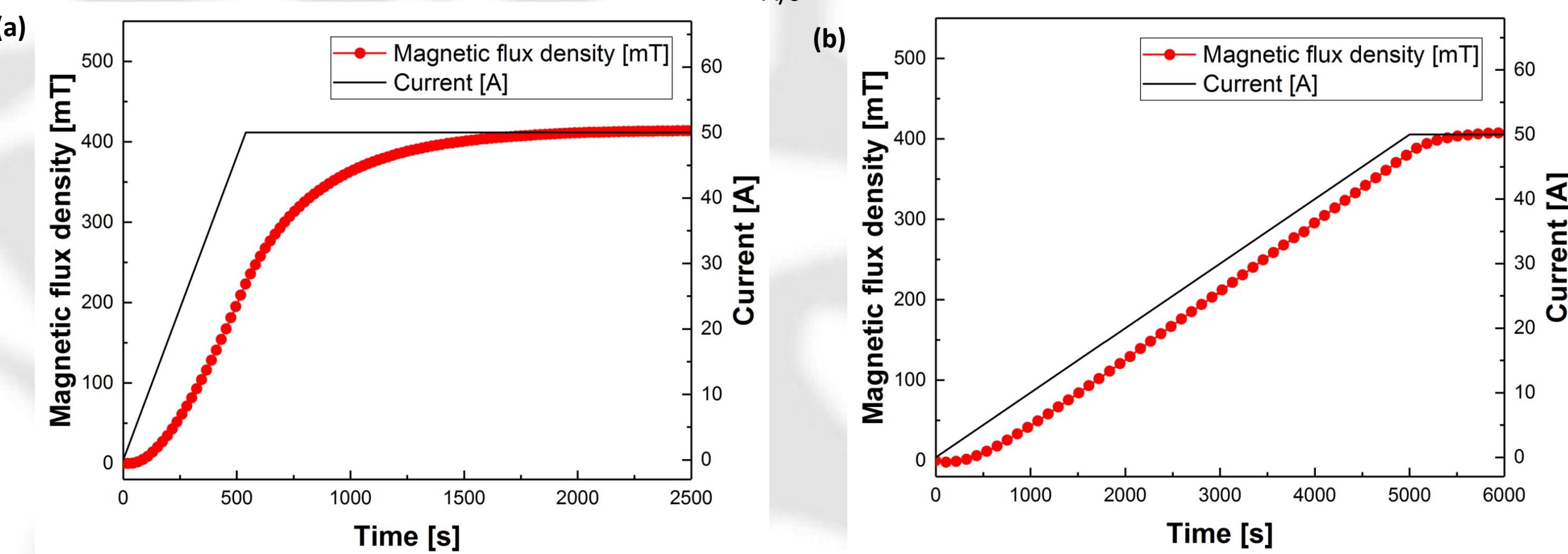
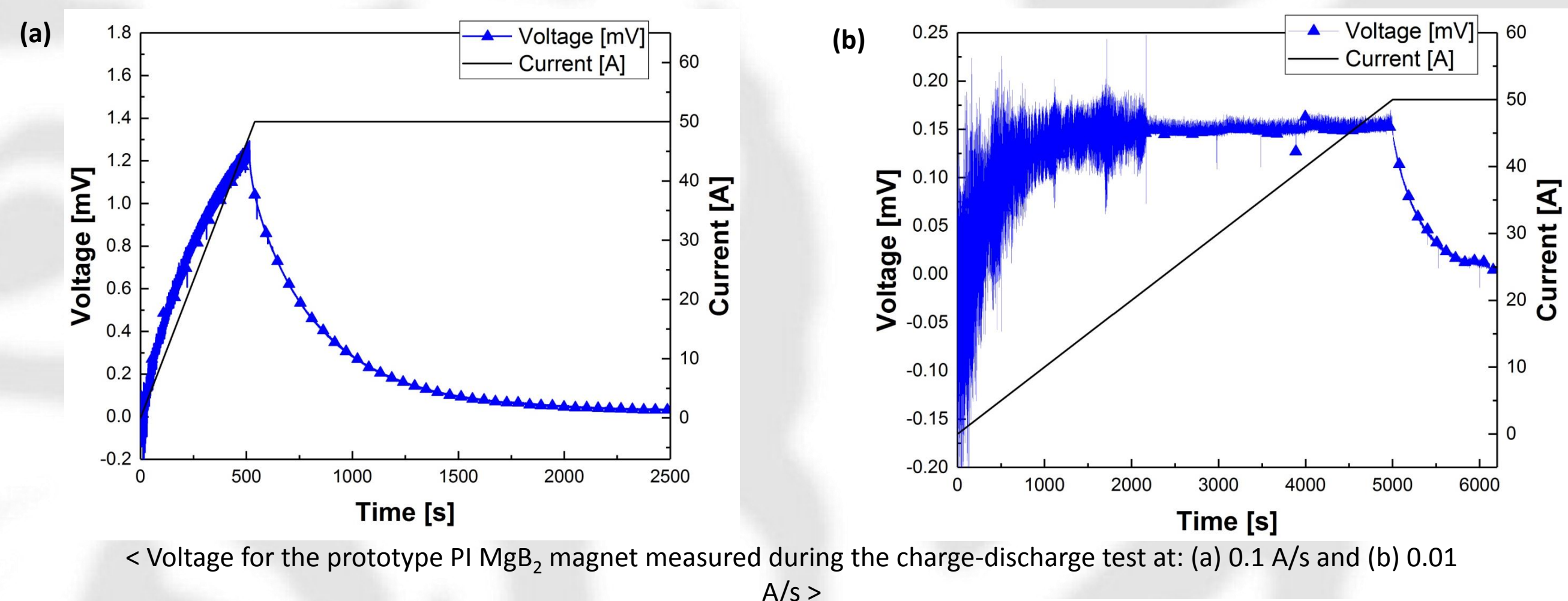
Parameters		Values
<i>Conductor</i>		
Material		MgB ₂
Diameter	[mm]	0.98
Manufacturer		K.A.T
<i>Magnet</i>		
Inner diameter	[mm]	52.74
Outer diameter	[mm]	71.24
Total height	[mm]	100
Turns; Layers		97; 8
Total conductor length	[m]	145.5
Operating temperature	[K]	4.2
Coil constant	[mT/A]	8.16
Inductance	[mH]	15.55



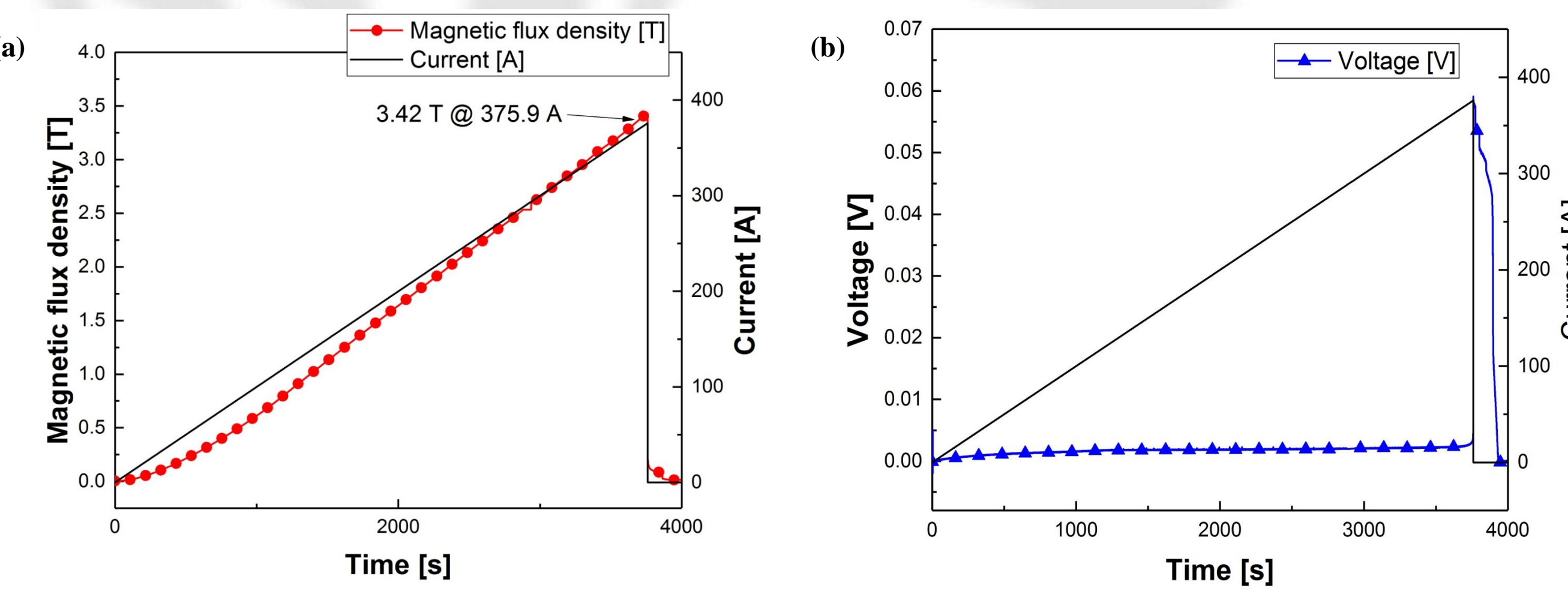
< Fabrication details for the prototype PI MgB₂ magnet >

Results & discussion

★ Test results for PI MgB₂ magnet

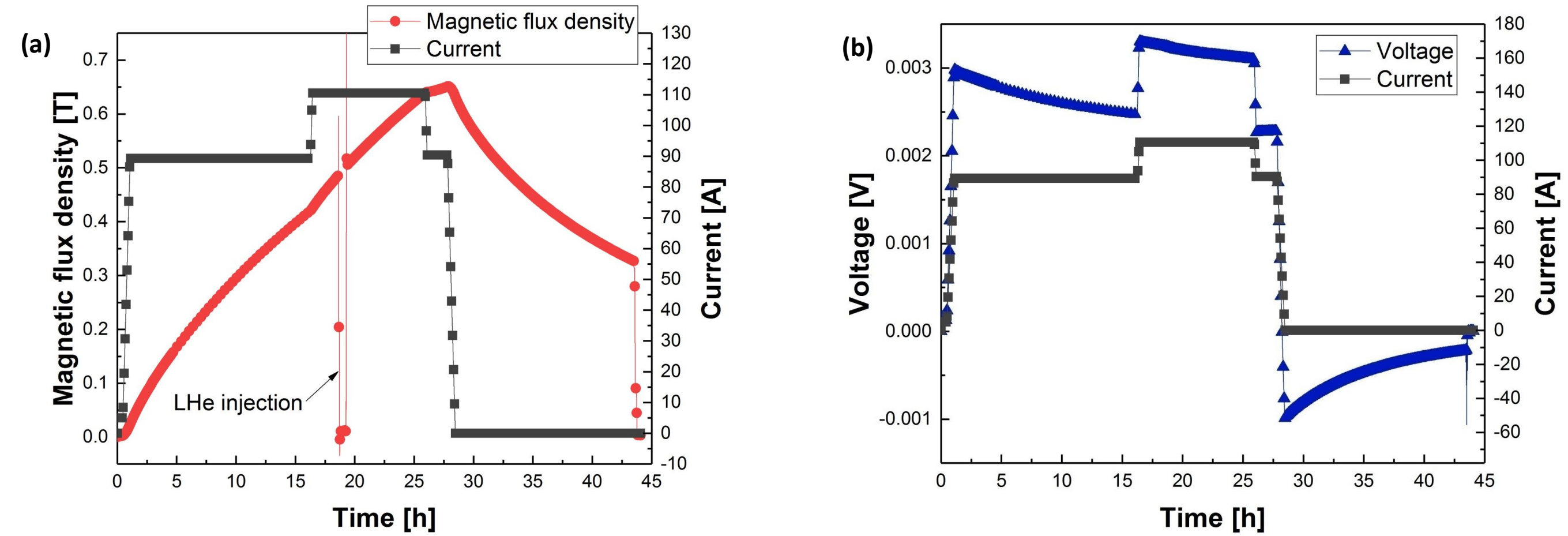
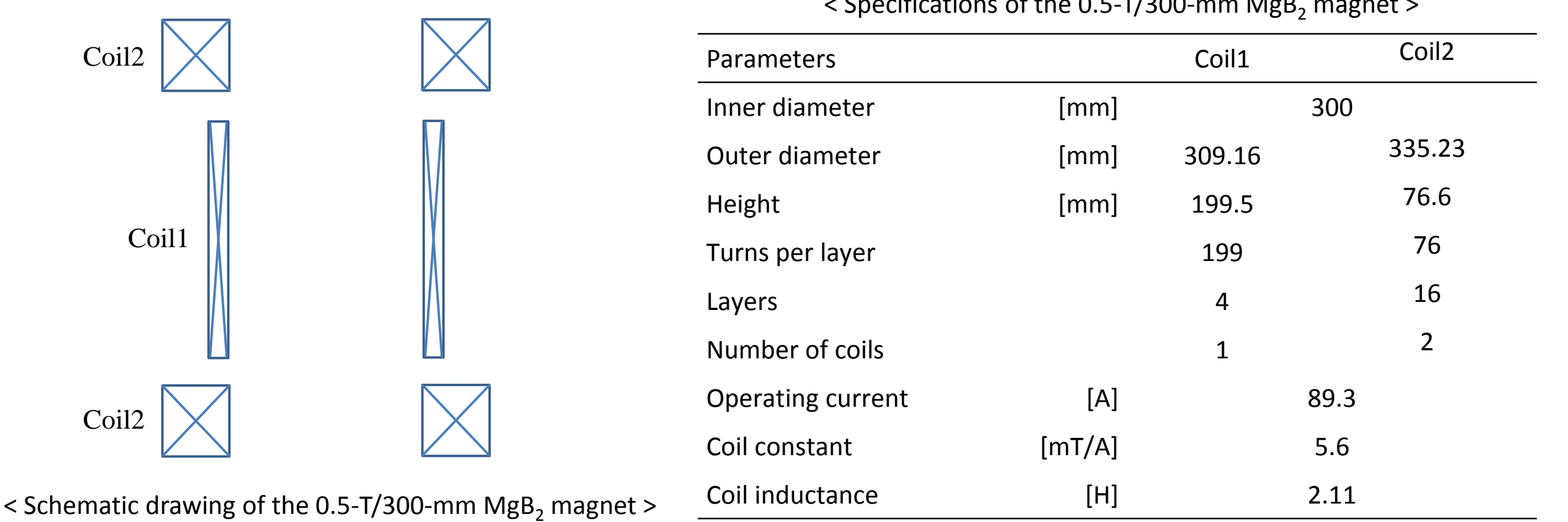


< Magnetic flux density for the prototype PI MgB₂ magnet measured during the charge-discharge test at: (a) 0.1 A/s and (b) 0.01 A/s >

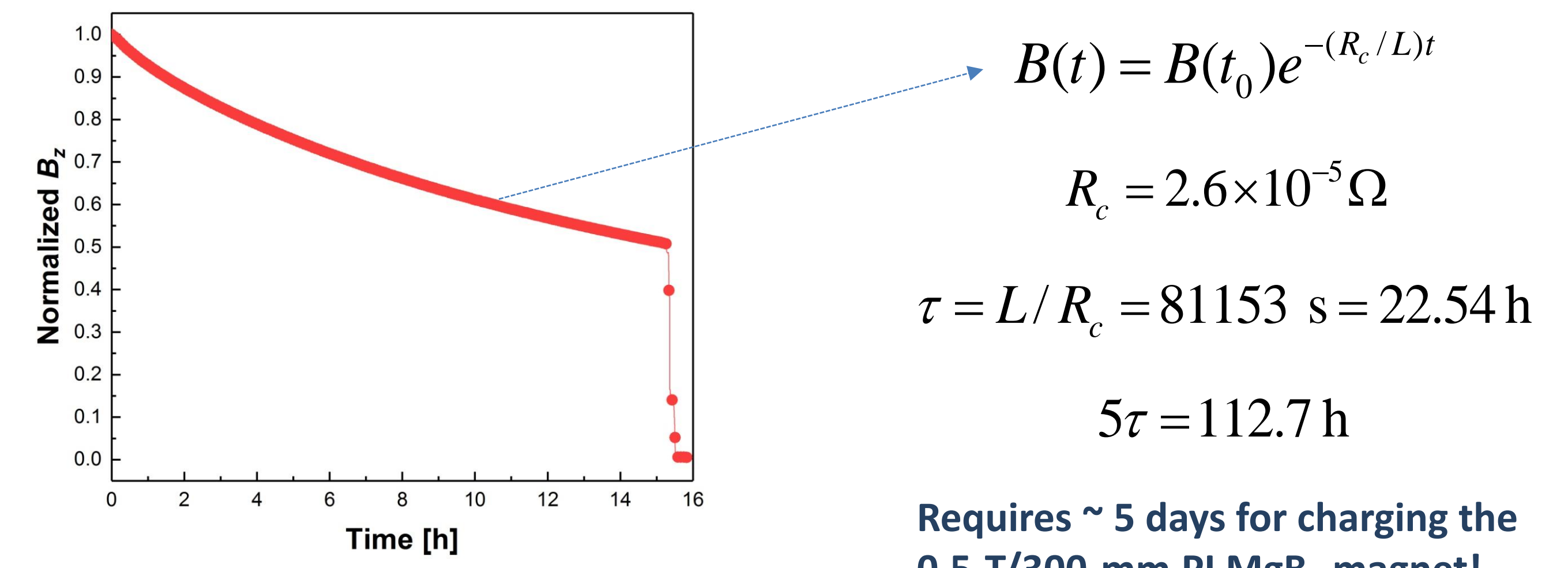


< Magnetic flux density (a) and voltage (b) for the prototype PI MgB₂ magnet measured during the over-current test >

★ 0.5-T/300-mm PI MgB₂ magnet



< Magnetic flux density (a) and voltage (b) for the 0.5-T/300-mm PI MgB₂ magnet >



< Sudden discharge test results for the 0.5-T/300-mm PI MgB₂ magnet >

$$B(t) = B(t_0)e^{-(R_c/L)t}$$
$$R_c = 2.6 \times 10^{-5} \Omega$$
$$\tau = L/R_c = 81153 \text{ s} = 22.54 \text{ h}$$
$$5\tau = 112.7 \text{ h}$$

Requires ~ 5 days for charging the 0.5-T/300-mm PI MgB₂ magnet!